TVS Diode

Transient Voltage Suppressor Diodes

ESD201-B2-03LRH

Bi-directional Dual Diode for ESD/Transient Protection

ESD201-B2-03LRH

Data Sheet

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Final

Power Management & Multimarket

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Revision History: Rev. 1.0, 2012-09-19	
Page or Item	**Subjects (major changes since previous revision)**
Revision 1.1, 2012-09-26	
3	Small changes in the Features

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Last Trademarks Update 2010-10-26

1 Bi-directional Dual Diode for ESD / Transient Protection

1.1 Features

- ESD / Transient protection of signal lines according to:
  - **IEC61000-4-2 (ESD): ±20 kV (air/contact discharge)**
  - **IEC61000-4-4 (EFT): 40 A (5/50 ns)**
  - **IEC61000-4-5 (surge): 2.5 A (8/20 µs)**
- Dual diode with small form factor of 0402 package size
- Bi-directional, symmetrical working voltage: V_{RWM} = ±5.5 V max.
- Low capacitance: C_L **= 5 pF typ**
- Very low clamping voltage, low dynamic resistance down to: R_{DYN} = 0.22 typ
- Pb-free (RoHS compliant) and halogen free package

1.2 Application Examples

- ESD protection to keypad, touchpad, buttons, audio lines, ect.

1.3 Product Description

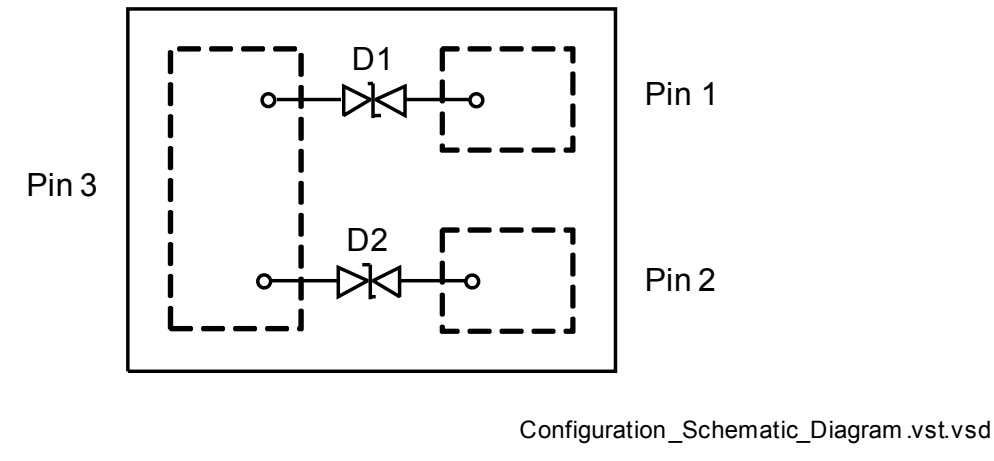


Figure 1-1 Pin Configuration and Schematic Diagram

Table 1-1 Ordering Information

Type	Package	Configuration	Marking code
ESD201-B2-03LRH	TSLP-3-9	2 line, bi-directional	44

2 Characteristics

2.1 Maximum Ratings

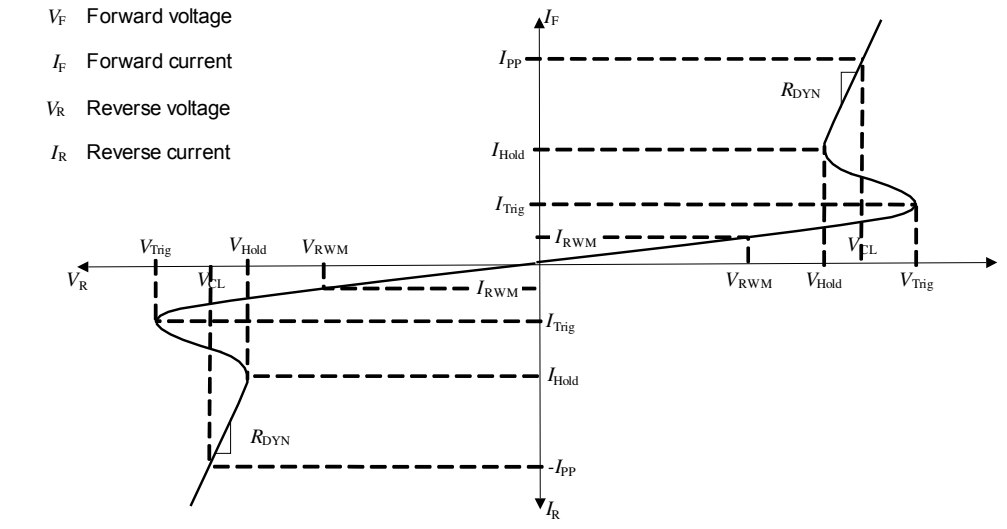
Table 2-1 Maximum Ratings at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
ESD air/contact discharge[1)]	V_{ESD}	-	-	20	kV
Operating temperature range	T_{OP}	-55	–	125	°C
Storage temperature	T_{stg}	-65	–	150	°C

1) V_{ESD} according to IEC61000-4-2 (R = 330 Ω, C = 150 pF discharge network)

Attention: Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit.

2.2 Electrical Characteristics at T_A = 25 °C, unless otherwise specified



R_{DYN}	Dynamic resistance	V_{FC}	Forward clamping voltage
V_{Trig}	Triggering reverse voltage	I_{Trig}	Triggering reverse current
V_{CL}	Clamping voltage	I_{Hold}	Holding reverse current
V_{Hold}	Holding reverse voltage	I_{PP}	Peak pulse current
V_{RWM}	Reverse working voltage maximum	I_{RWM}	Reverse working current maximum

Figure 2-1 Definitions of electrical characteristics

Table 2-2 DC Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Reverse working voltage	V_{RWM}	-5.5	–	5.5	V	
Reverse current	I_R	–	–	100	nA	V_R = 5.5 V

Table 2-3 AC Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Line capacitance to GND	C_L	–	5	7	pF	V_R = 0 V, f = 1 MHz

Table 2-4 ESD Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clamping voltage[1)] Pin1 or Pin2 to Pin3 (GND) Pin3 (GND) to Pin1 or Pin2	V_{CL}	 – –	 12.1 10.2	 – –	V	t_p = 100 ns I_{PP} = 16 A I_{PP} = 16 A
Dynamic resistance[1)] Pin1 or Pin2 to Pin3 (GND) Pin3 (GND) to Pin1 or Pin2	R_{DYN}	 – –	 0.37 0.22	 – –	Ω	t_p = 100 ns

1) Please refer to Application Note AN210[1]. TSLP parameter:Z_0 = 50 Ω, t_p = 100 ns, $t_{r,}$ = 300 ps

3 Typical Characteristics

The curves are all specified at T_A = 25 °C

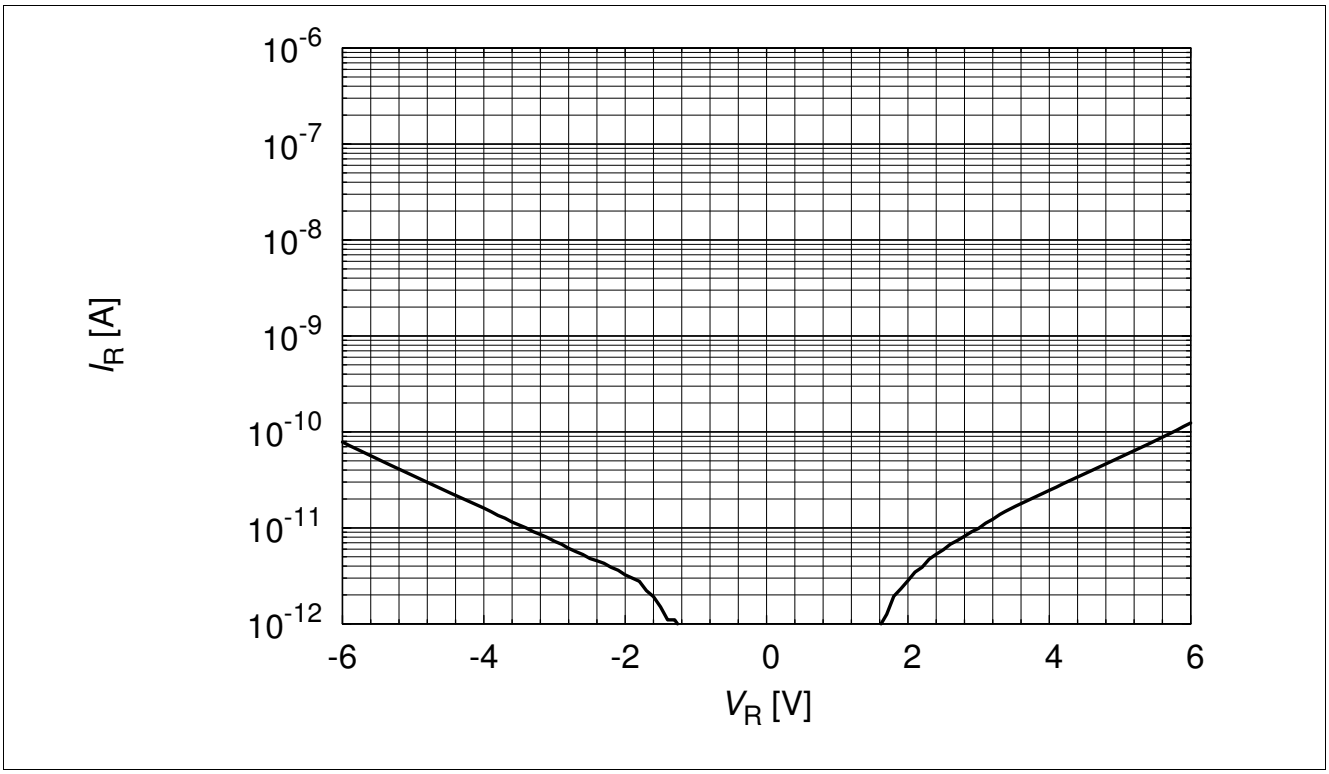


Figure 3-1 Reverse current: $I_R = f(V_R)$

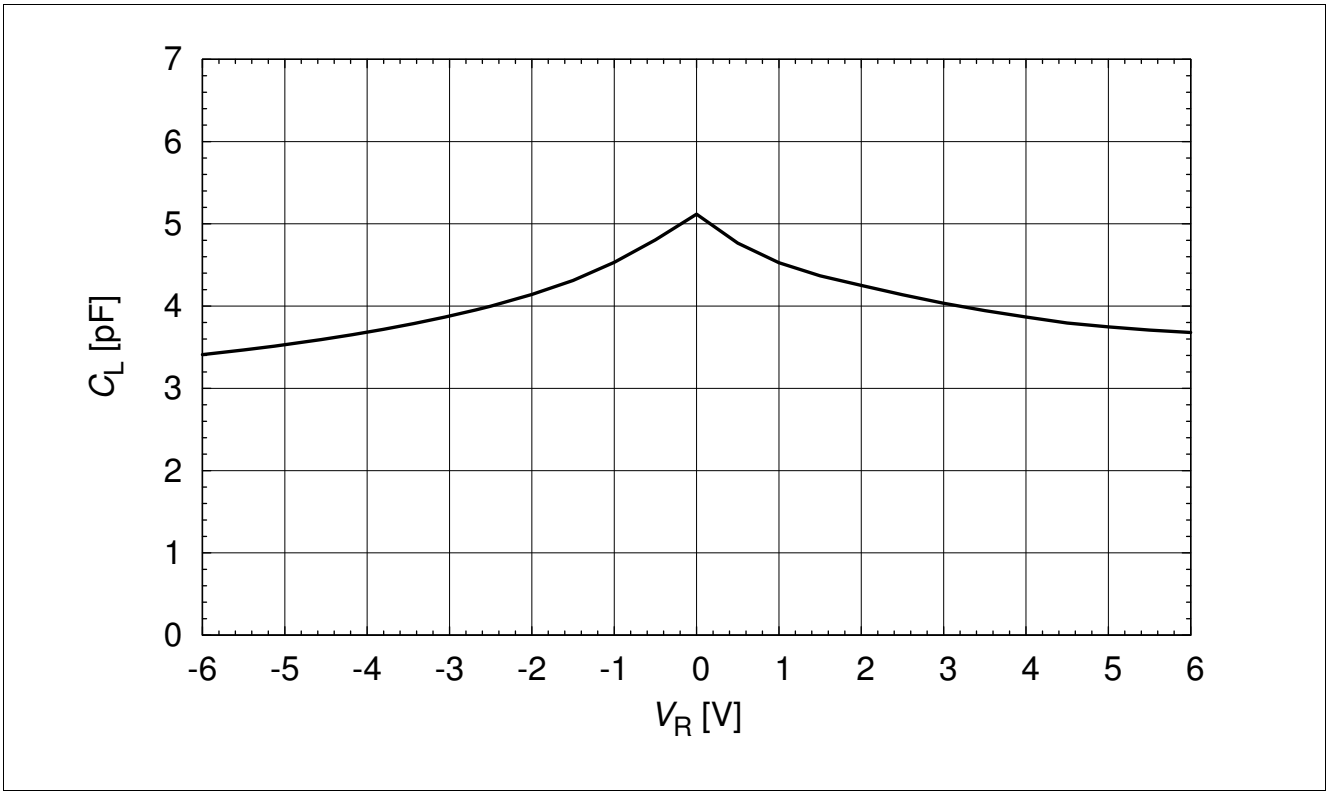


Figure 3-2 Line capacitance $C_L = f(V_R), f$ = 1 MHz

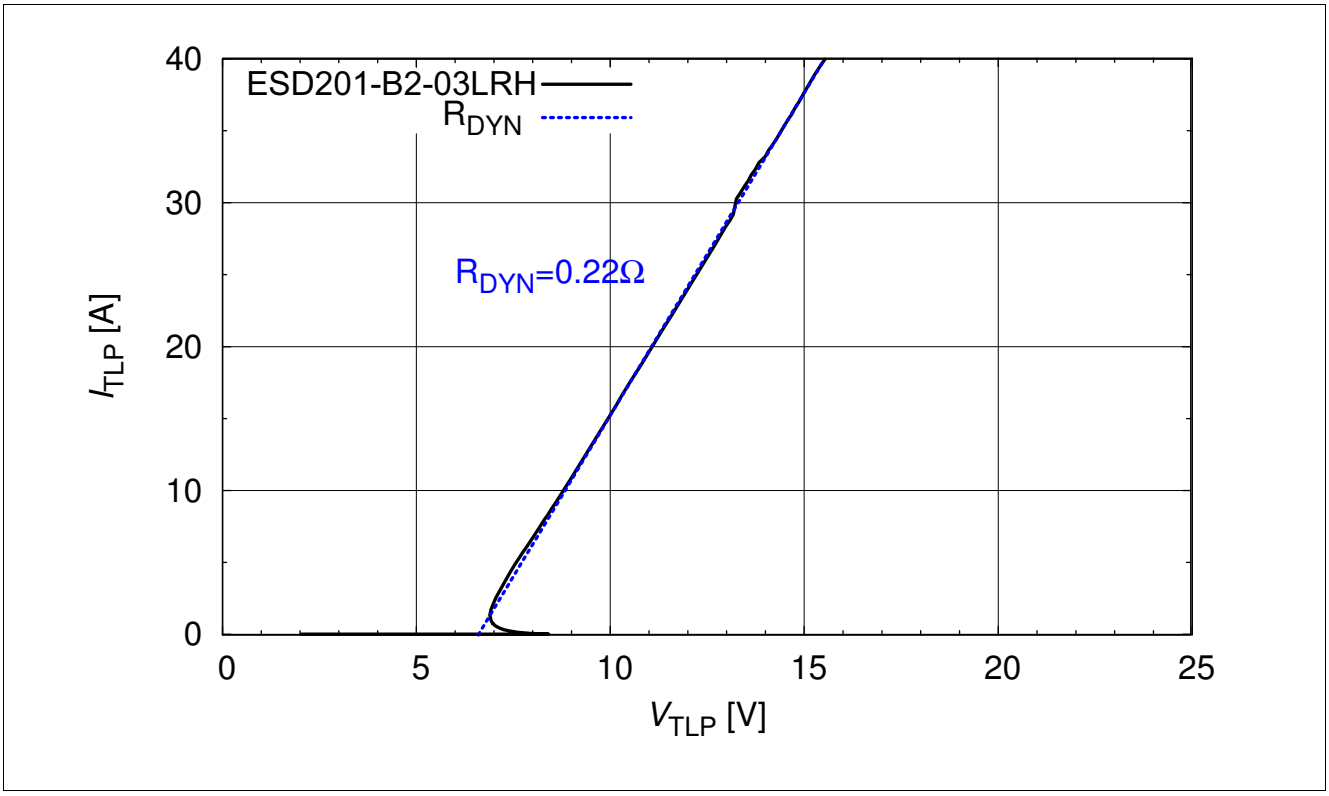


Figure 3-3 Clamping voltage (TLP): $I_{TLP} = f(V_{TLP})$ GND to Line

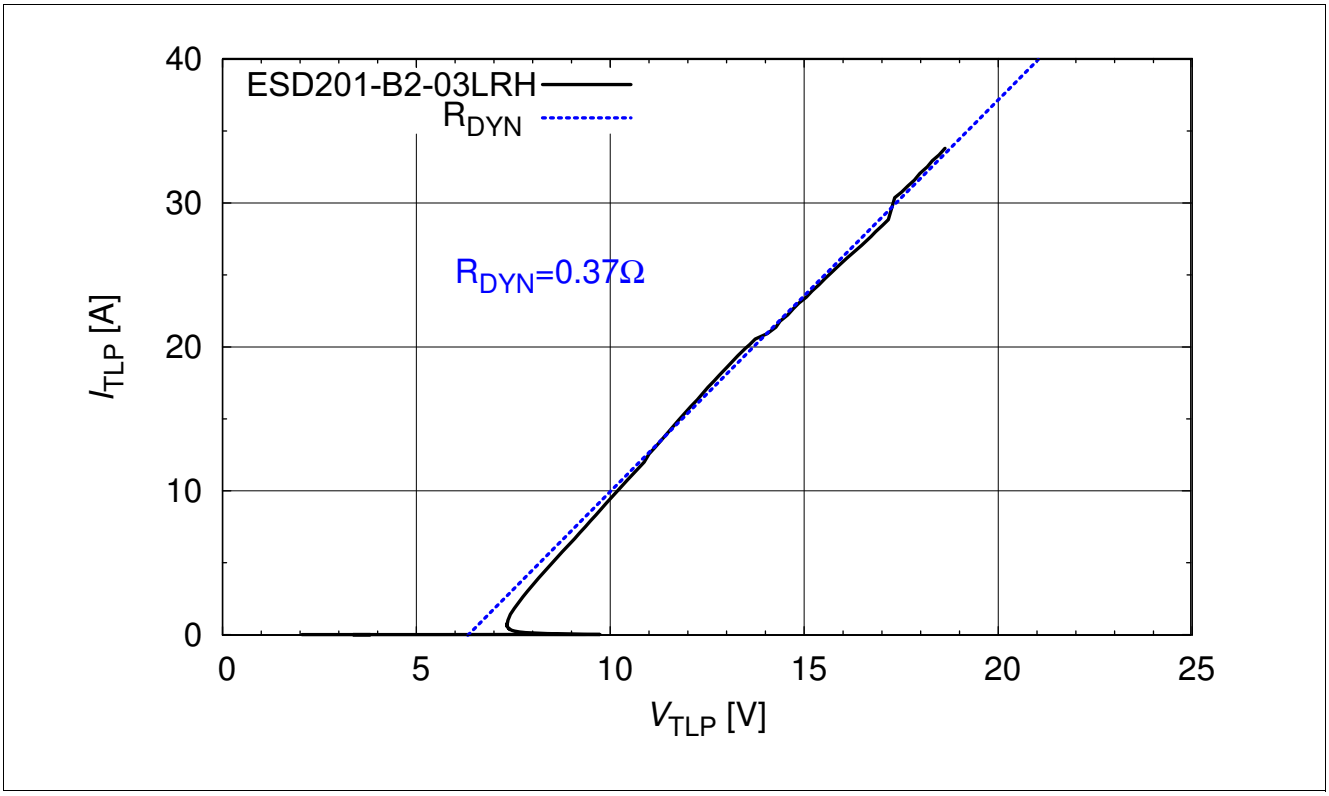


Figure 3-4 Clamping voltage (TLP): $I_{TLP} = f(V_{TLP})$ Line to GND

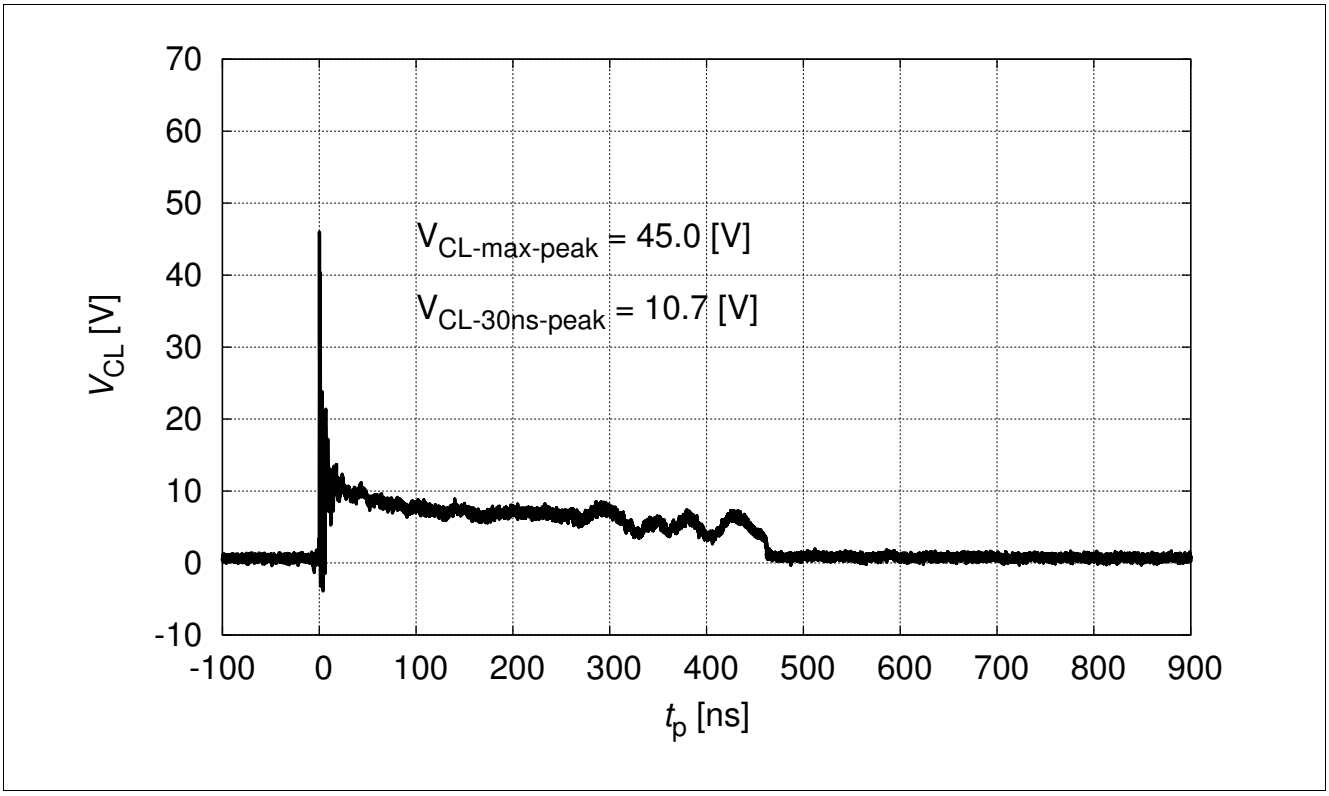


Figure 3-5 IEC61000-4-2: $V_{CL} = f(t)$, 8 kV positive pulse

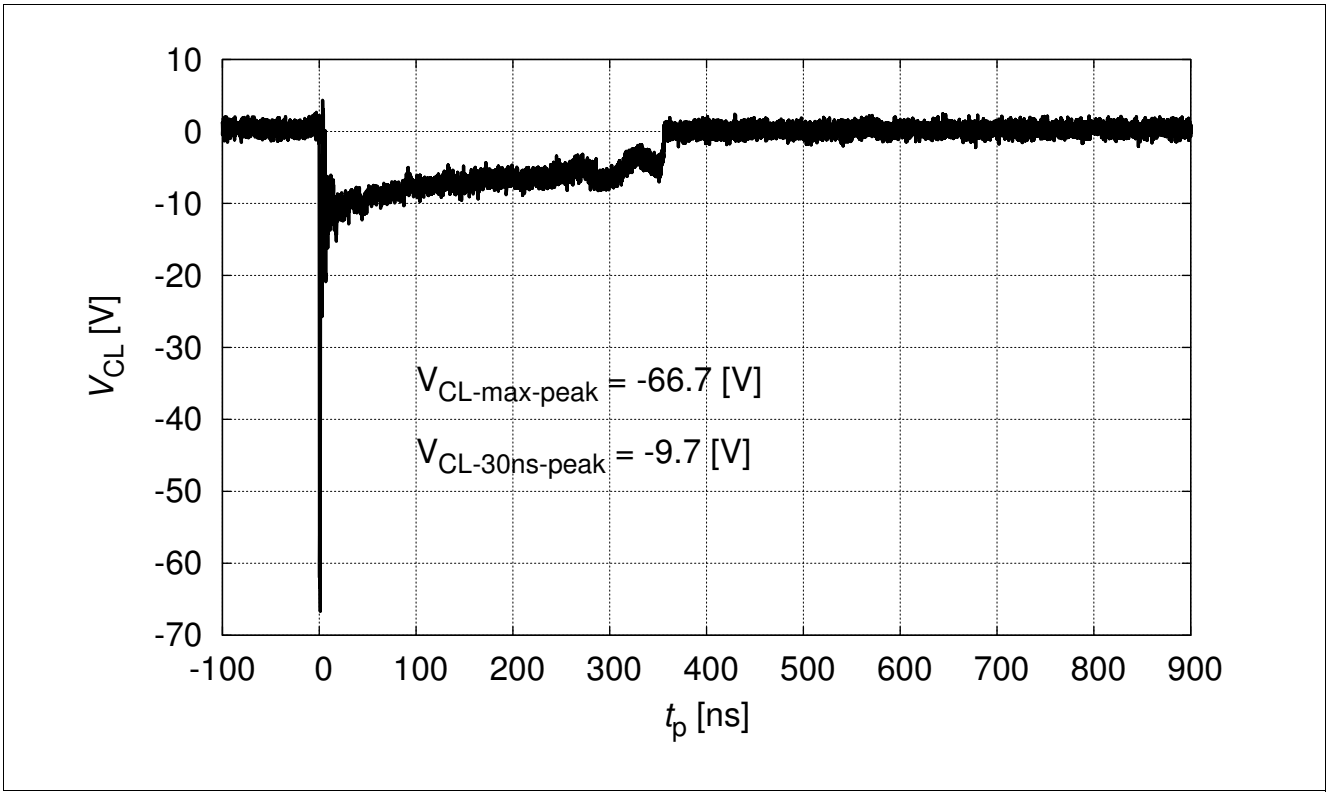


Figure 3-6 IEC61000-4-2: $V_{CL} = f(t)$, 8 kV negative pulse

4 Package Information

4.1 TSLP-3-9

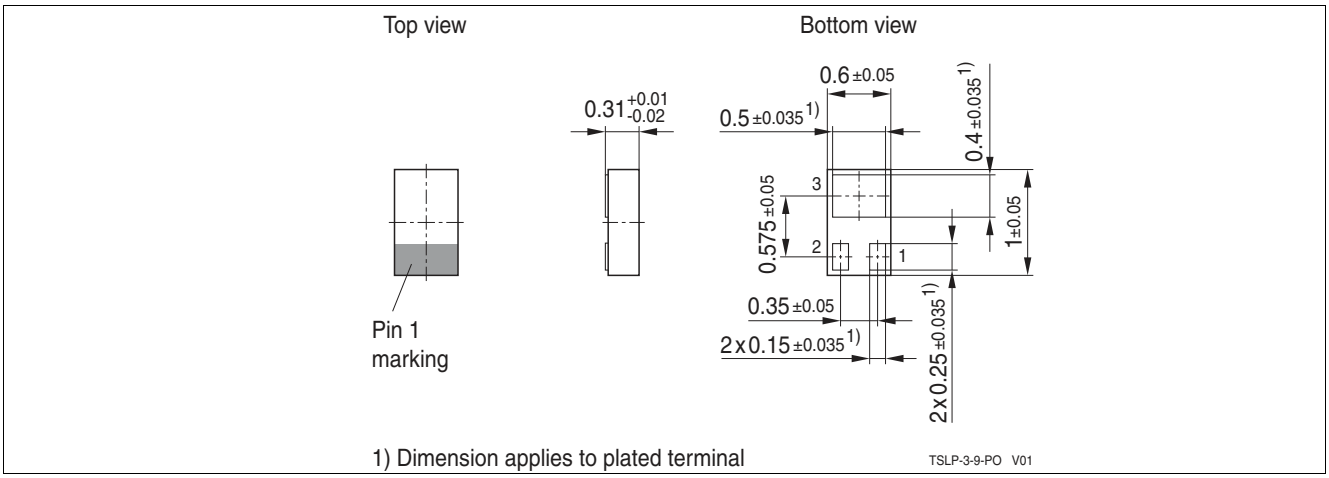


Figure 4-1 TSLP-3-9 Package outline

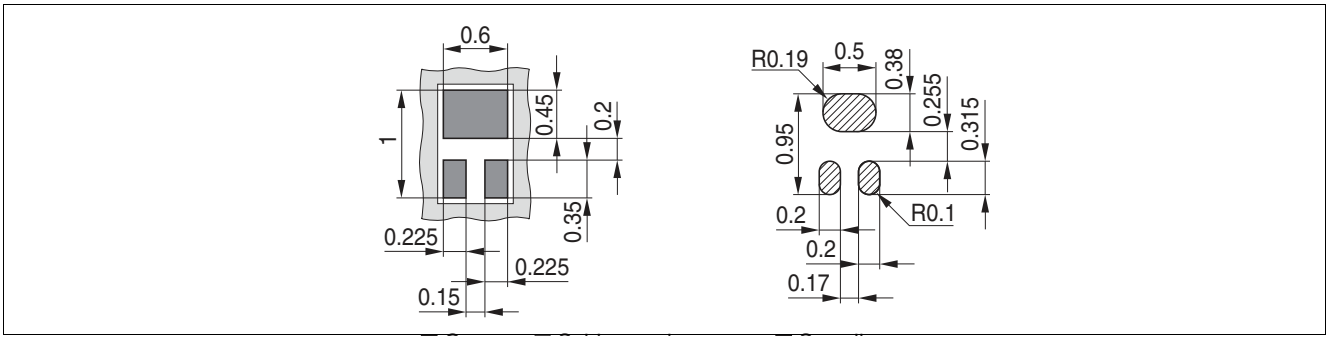


Figure 4-2 TSLP-3-9 Footprint

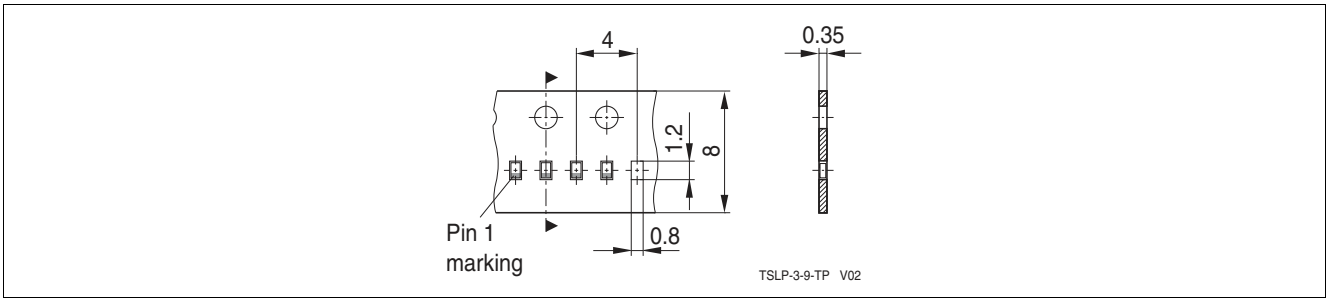


Figure 4-3 TSLP-3-9 Packing

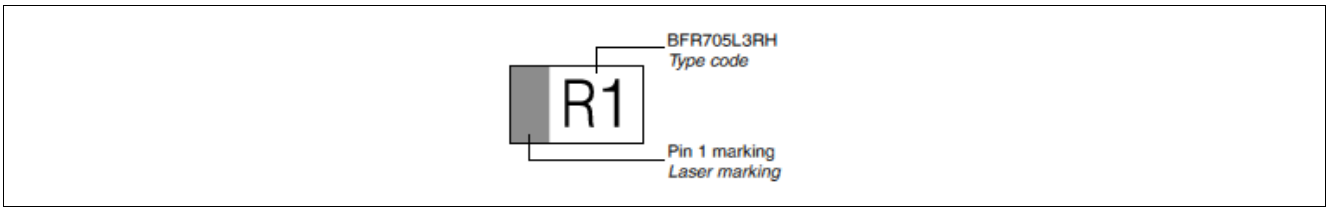


Figure 4-4 TSLP-3-9 Marking (example)

References

[1] Infineon AG - **Application Note AN210:** Effective ESD Protection design at System Level Using VF-TLP Characterization Methodology

[2] Infineon AG - Recommendations for PCB Assembly of Infineon TSLP and TSSLP Packages

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